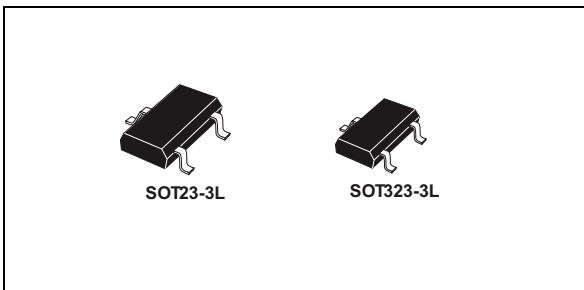


## Precision micropower shunt voltage reference

Datasheet - production data



### Features

- Fixed 1.225 V, 1.25 V output voltages
- Ultra low operating current: 10  $\mu$ A at 25 °C
- High precision @ 25 °C: +/-0.1% (TS4061A),  
+/- 0.2% (TS4061B)
- Very low LF noise: typ.10  $\mu$  V<sub>p-p</sub>
- Stable when used with capacitive loads
- Industrial (-40 to +85 °C) temperature range
- 35 ppm/°C max. temperature coefficient
- Available in SOT23-3L and SOT323-3L  
packages

### Description

The TS4061 is a low power and high accuracy shunt voltage reference providing a stable output voltage over the industrial temperature range (-40 to +85 °C), with a maximum temperature coefficient of 35 ppm/°C. It is available in 0.1% and 0.2% initial accuracy versions. The SOT323-3L and SOT23-3L packages can be designed in applications where space saving is a critical issue. The very low operating current is a key advantage for power restricted designs. The TS4061 is very stable and can be used in a broad range of application conditions.

### Applications

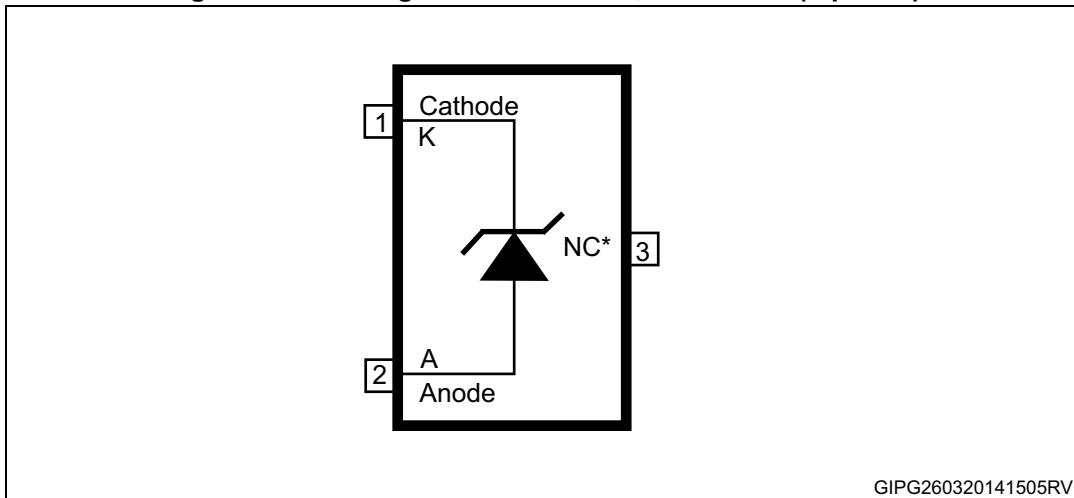
- Portable, battery-operated equipment
- Data acquisition systems
- Instrumentation

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## 1 Pin configuration

Figure 1. Pin configuration SOT23-3L, SOT323-3L (top view)



Note: The NC pin has to be connected to GND.

## 2 Maximum ratings

Table 1. Absolute maximum ratings

Symbol	Parameter	Value	Unit
$I_k$	Reverse breakdown current	20	mA
$I_f$	Forward current	15	mA
$P_d$	Power dissipation <sup>(1)</sup>	500	mW
$T_{std}$	Storage temperature	-65 to +150	°C
$E_{SD}$	Human body model (HBM)	2	kV
	Machine model (MM)	200	V
	Charged device model	1500	V
$T_{lead}$	Lead temperature (soldering) 10 sec	260	°C
$T_j$	Max. junction temperature	+150	°C

1.  $P_d$  has been calculated with  $T_{amb} = 25$  °C and  $T_{jmax} = 150$  °C

Note: *Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.*

Table 2. Thermal data

Symbol	Parameter	SOT323-3L	SOT23-3L	Unit
$R_{thJA}$	Thermal resistance junction-ambient	246	242	°C/W
$R_{thJC}$	Thermal resistance junction-case	171	103	°C/W

Table 3. Operating conditions

Symbol	Parameter	Value	Unit
$I_{kmin}$	Minimum operating current	10	µA
$I_{kmax}$	Maximum operating current	15	mA
$T_{oper}$	Operating free air temperature range	-40 to +85	°C

### 3 Electrical characteristics

Limits are 100% production tested at 25 °C. Limits over full temperature range are guaranteed through correlation and by design.  $I_k = 10 \mu A$ ,  $T_{amb} = 25 \text{ }^{\circ}\text{C}$  (unless otherwise specified).

**Table 4. Electrical characteristics for TS4061**

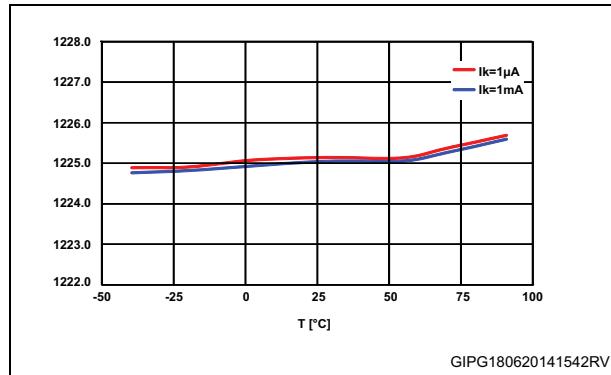
Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_k$	Reverse breakdown voltage ( $V_k = 1.225 \text{ V}$ )	$I_k = 10 \mu A$ , TS4061A	1.2237	1.225	1.2262	$\text{V}$
		$I_k = 10 \mu A$ , TS4061B	1.2225		1.2275	
	Reverse breakdown voltage ( $V_k = 1.25 \text{ V}$ )	$I_k = 10 \mu A$ , TS4061A	1.2487	1.25	1.2512	$\text{V}$
		$I_k = 10 \mu A$ , TS4061B	1.2475		1.2525	
$I_{kmin}$	Minimum operating current	$T_{amb} = 25 \text{ }^{\circ}\text{C}$		7.5	10	$\mu A$
		$-40 \text{ }^{\circ}\text{C} < T_{amb} < +85 \text{ }^{\circ}\text{C}$			12	
$\Delta V_k/\Delta T$	Average temperature coefficient	$10 \mu A < I_k < 15 \text{ mA}$		20	35	$\text{ppm}/^{\circ}\text{C}$
$\Delta V_k/\Delta I_k$	Reverse breakdown voltage change with operating current range	$I_{kmin} < I_k < 1 \text{ mA}$ $-40 \text{ }^{\circ}\text{C} < T_{amb} < +85 \text{ }^{\circ}\text{C}$		0.2	1	$\text{mV}$
		$1 \text{ mA} < I_k < 15 \text{ mA}$ $-40 \text{ }^{\circ}\text{C} < T_{amb} < +85 \text{ }^{\circ}\text{C}$		1.7	4	
$R_{ka}$	Static impedance	$\Delta I_k = 10 \mu A \text{ to } 10 \text{ mA}$		0.15	0.3	$\Omega$
Hys	Thermal hysteresis <sup>(1)</sup>	$I_k = 10 \mu A$		120		$\text{ppm}$
Noise	Wideband noise	$I_k = 10 \mu A$ $10 \text{ Hz} < f < 10 \text{ kHz}$		95		$\mu\text{VRMS}$
	Low frequency noise	$I_k = 10 \mu A$ $0.1 \text{ Hz} < f < 10 \text{ Hz}$		10		$\mu\text{Vp-p}$

1. Thermal hysteresis is defined as the difference in voltage measured at  $+25 \text{ }^{\circ}\text{C}$  after cycling to  $-40 \text{ }^{\circ}\text{C}$  and the measurement at  $+25 \text{ }^{\circ}\text{C}$  after cycling to temperature  $+85 \text{ }^{\circ}\text{C}$ .

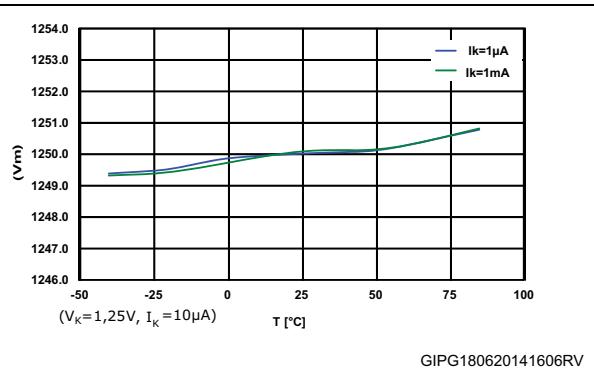
## 4 Typical performance characteristics

(The following plots are referred to the typical application circuit and, unless otherwise noted, at  $T_A = 25^\circ\text{C}$ )

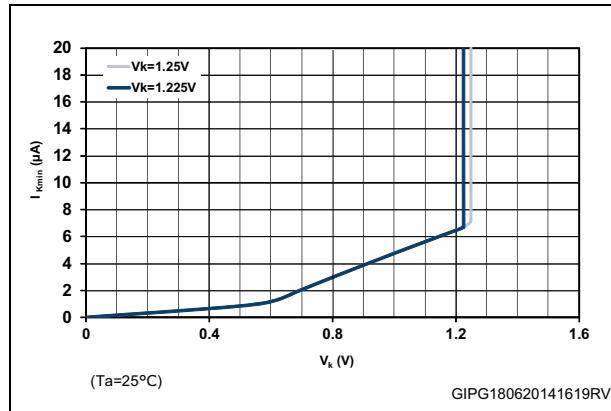
**Figure 2.  $V_K$  change vs temperature (1.225 V version)**



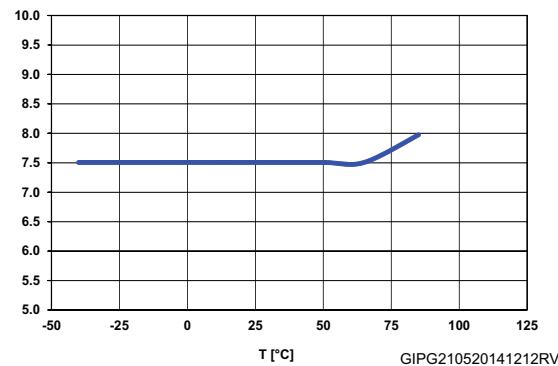
**Figure 3.  $V_K$  change vs temperature (1.25 V version)**



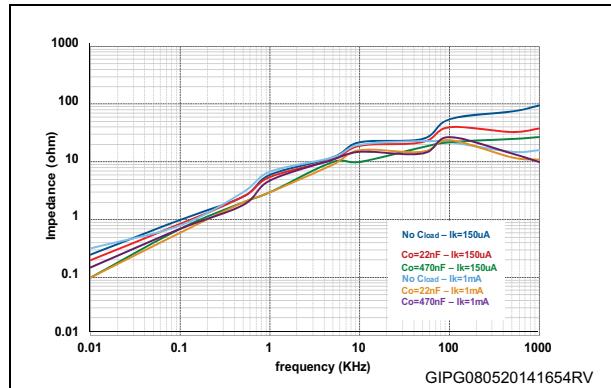
**Figure 4.  $I_{Kmin}$  minimum current for regulation**



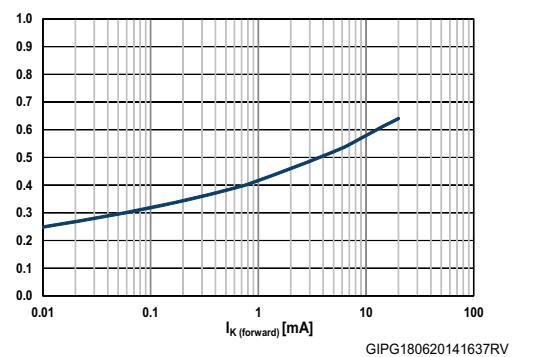
**Figure 5.  $I_{Kmin}$  minimum current for regulation vs temperature**

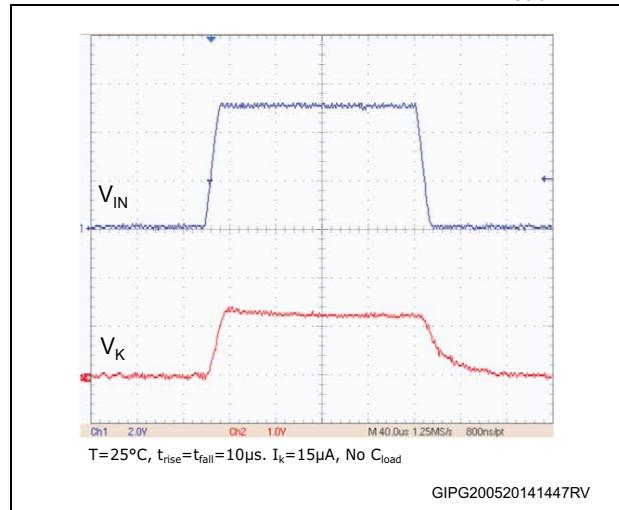
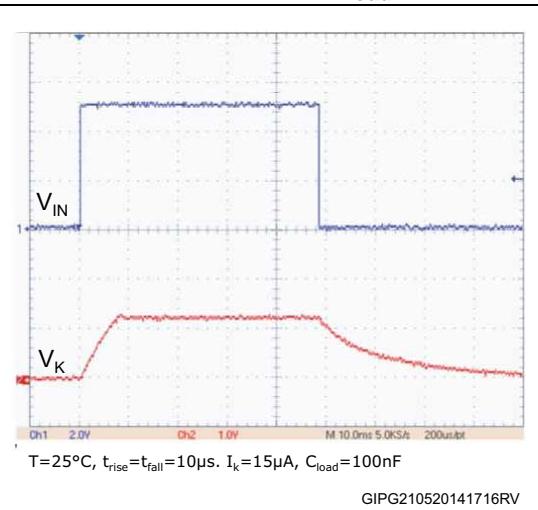
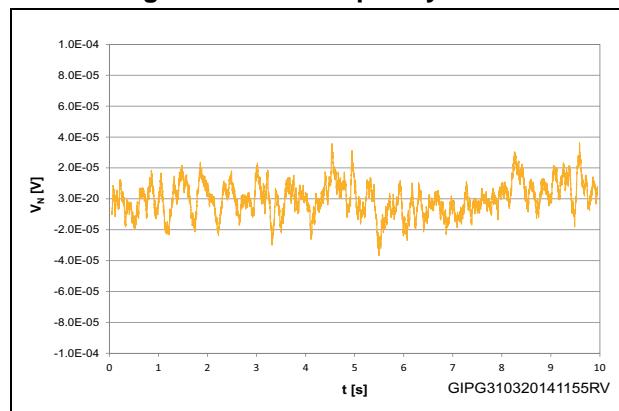


**Figure 6. Output impedance vs frequency**



**Figure 7. Forward characteristics**



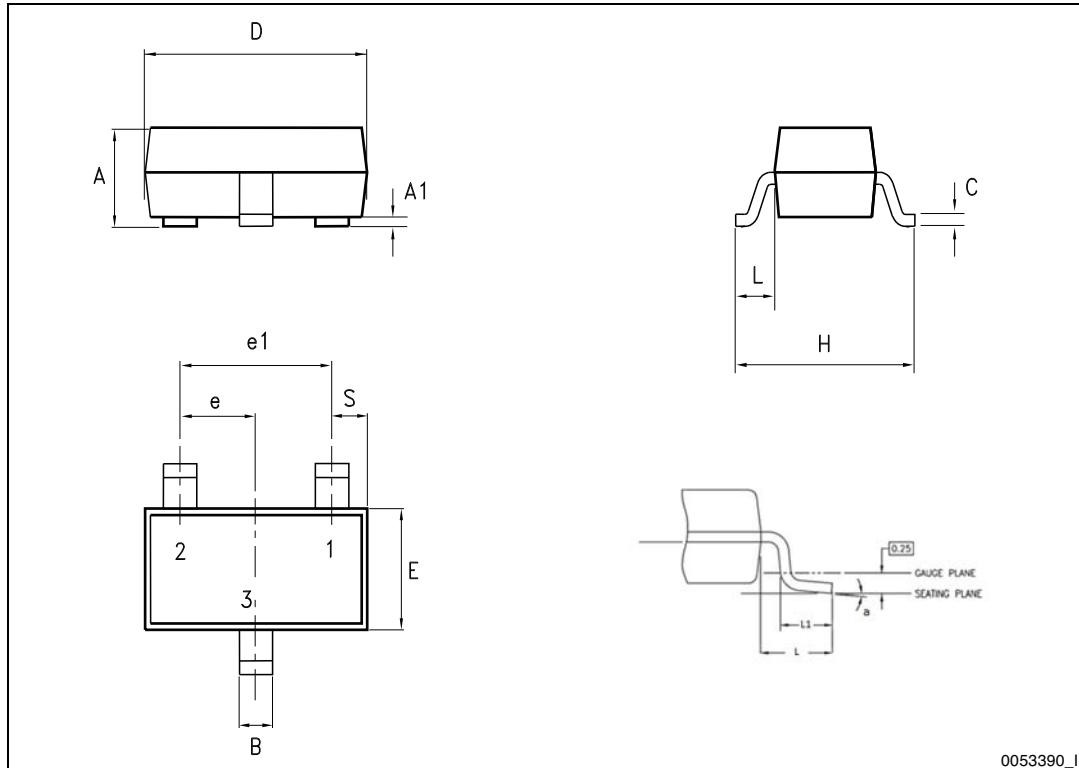
**Figure 8. Start-up waveform (no  $C_{load}$ )****Figure 9. Start-up waveform ( $C_{load} = 100$  nF)****Figure 10. Low frequency noise**

## 5 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com).  
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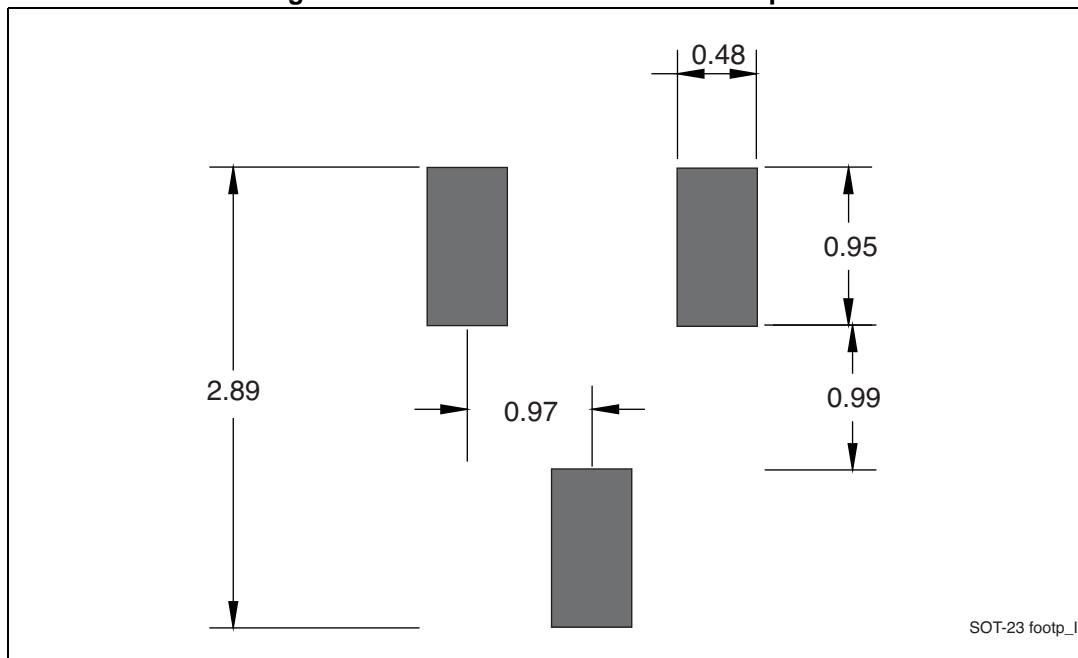
### 5.1 SOT23-3L, TS4061

Figure 11. SOT23-3L mechanical drawings



**Table 5. SOT23-3L mechanical data**

Dim.	mm		
	Min.	Typ.	Max.
A	0.89		1.40
A1	0		0.10
B	0.30		0.51
C	0.085		0.18
D	2.75		3.04
e	0.85		1.05
e1	1.70		2.10
E	1.20		1.75
H	2.10		3.00
L		0.60	
S	0.35		0.65
L1	0.25		0.55
a	0°		8°

**Figure 12. SOT23-3L recommended footprint**

## 5.2 SOT323-3L, TS4061

Figure 13. SOT323-3L drawings

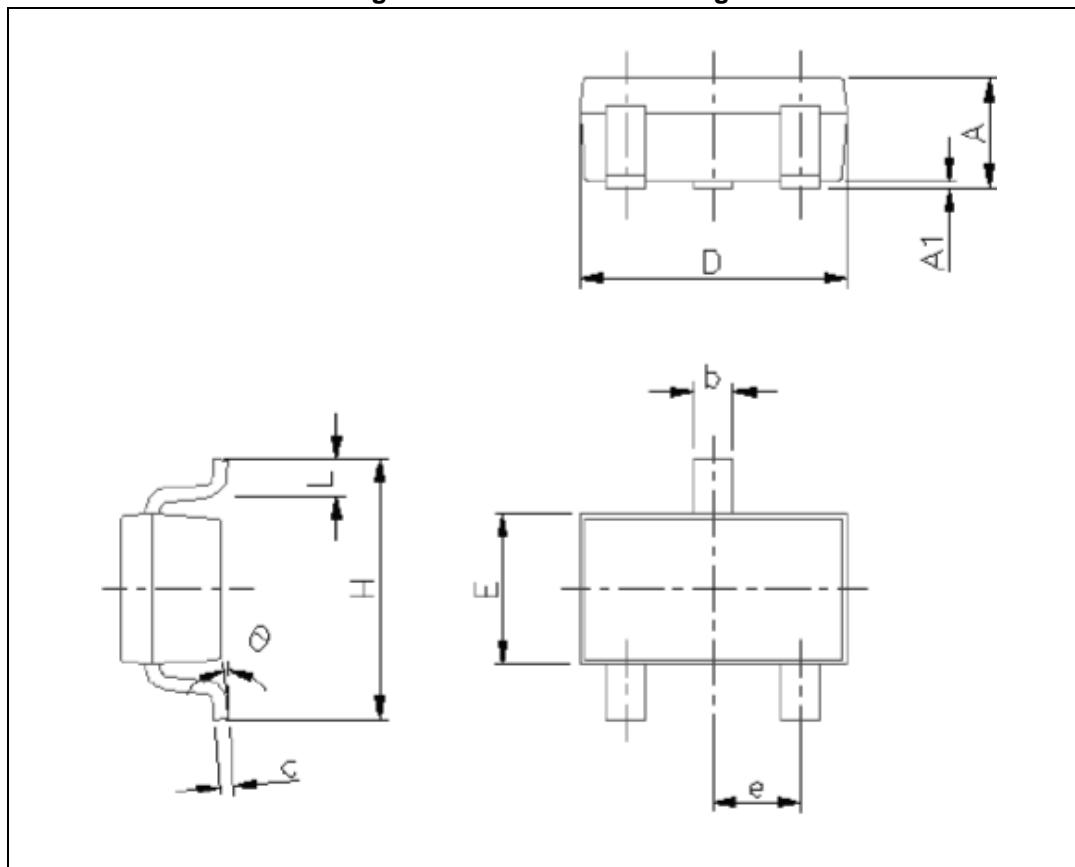
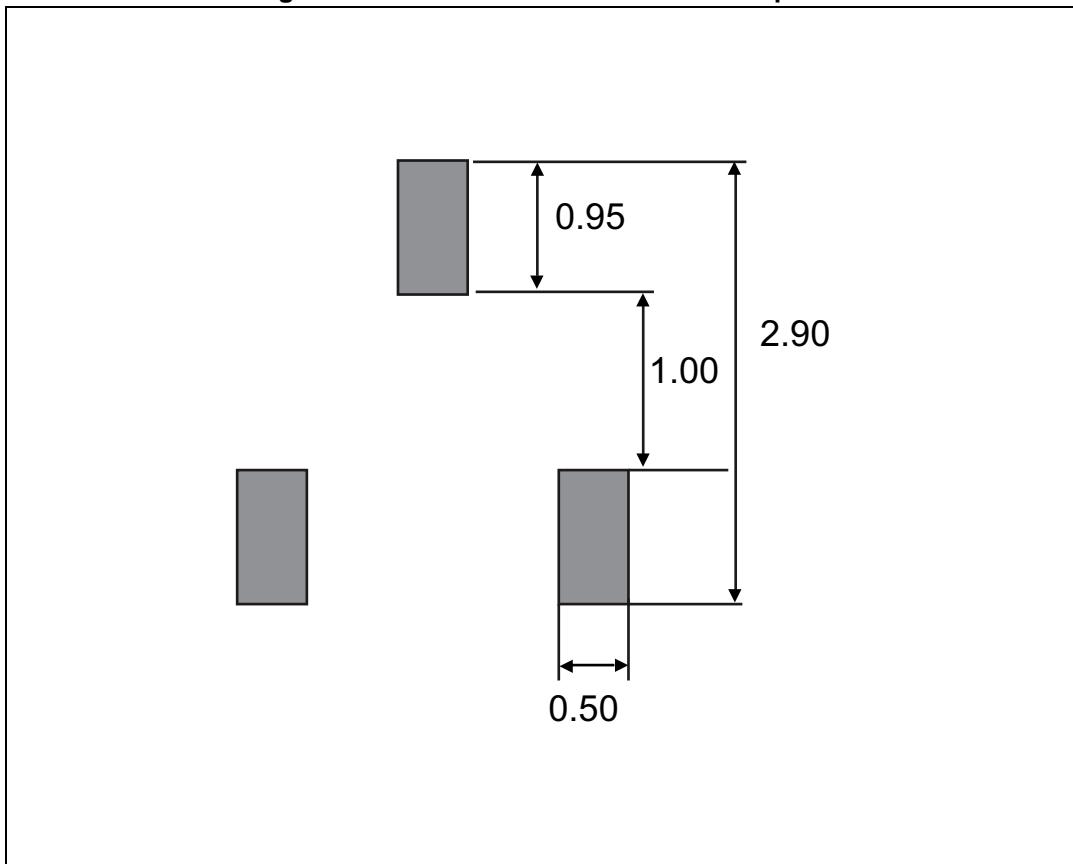


Table 6. SOT323-3L mechanical data

Dim.	mm		
	Typ.	Min.	Max.
A		0.80	1.10
A1		0.00	0.10
b		0.25	0.40
c		0.10	0.18
D		1.80	2.20
E		1.15	1.35
e	0.65	0.60	0.70
H		1.80	2.40
L		0.10	0.30

**Figure 14. SOT323-3L recommended footprint**

## 6 Ordering information

Table 7. Order codes

Order codes	Output voltage (V)	Precision (%)	Package	Temperature range (°C)
TS4061AILT-1.25	1.25	0.1	SOT23-3L	-40 to +85
TS4061AILT-1.225	1.225			
TS4061AICT-1.25	1.25	0.1	SOT323-3L	-40 to +85
TS4061AICT-1.225	1.225			
TS4061BILT-1.25	1.25	0.2	SOT23-3L	-40 to +85
TS4061BILT-1.225	1.225			
TS4061BICT-1.25	1.25	0.2	SOT323-3L	-40 to +85
TS4061BICT-1.225	1.225			

## 7 Revision history

**Table 8. Document revision history**

Date	Revision	Changes
21-Jul-2014	1	Initial release.

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